

GaAs pHEMT MMIC 2 WATT POWER AMPLIFIER WITH POWER DETECTOR, 12 - 16 GHz



Typical Applications

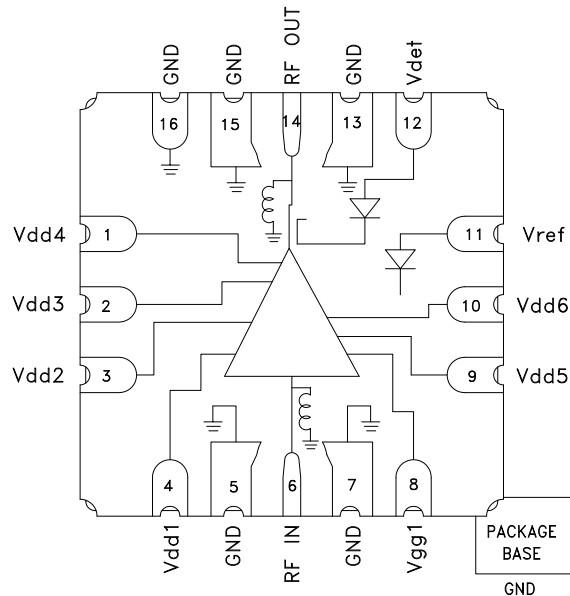
The HMC5846LS6 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- VSAT & SATCOM
- Military & Space

Features

- Saturated Output Power: 35.5 dBm @ 30% PAE
- High Output IP3: 42.5 dBm
- High Gain: 31 dB
- DC Supply: +7V @ 1200 mA
- No External Matching Required

Functional Diagram



General Description

The HMC5846LS6 is a 4 stage GaAs pHEMT MMIC 2 Watt Power Amplifier with an integrated temperature compensated power detector which operates between 12 and 16 GHz. The HMC5846LS6 provides 31 dB of gain, 35.5 dBm of saturated output power, and 30% PAE from a +7V supply. The HMC5846LS6 exhibits excellent linearity and is optimized for high capacity digital microwave radio. It is also ideal for 13.75 to 14.5 GHz Ku Band VSAT transmitters as well as SATCOM applications.

Electrical Specifications, $T_A = +25^\circ\text{C}$

$V_{dd} = V_{dd1}, V_{dd2}, V_{dd3}, V_{dd4}, V_{dd5} = +7V, I_{dd} = 1200\text{ mA}$ [1]

| Parameter | Min. | Typ. | Max. | Units |
|---|---------|------|------|--------|
| Frequency Range | 12 - 16 | | | GHz |
| Gain | 26 | 31 | | dB |
| Gain Variation Over Temperature | | 0.06 | | dB/ °C |
| Input Return Loss | | 10 | | dB |
| Output Return Loss | | 17 | | dB |
| Output Power for 1 dB Compression (P1dB) | 32.5 | 34.5 | | dBm |
| Saturated Output Power (P _{sat}) | | 35.5 | | dBm |
| Output Third Order Intercept (IP3) ^[2] | | 42.5 | | dBm |
| Total Supply Current (I _{dd}) | | 1200 | | mA |

[1] Adjust V_{gg} between -2 to 0V to achieve I_{dd} = 1200 mA typical.

[2] Measurement taken at +7V @ 1200 mA, P_{out} / Tone = +22 dBm

HMC5846* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- HMC5846LS6 Evaluation Board

DOCUMENTATION

Data Sheet

- HMC5846 Data Sheet

TOOLS AND SIMULATIONS

- HMC5846 S-Parameter

REFERENCE MATERIALS

Quality Documentation

- Package/Assembly Qualification Test Report: 20L 7x7mm Ceramic LCC Package (QTR: 11005P REV: 03)
- Semiconductor Qualification Test Report: PHEMT-E (QTR: 2013-00259)

DESIGN RESOURCES

- HMC5846 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC5846 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

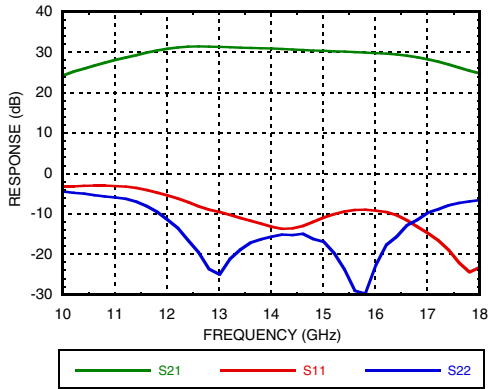
DOCUMENT FEEDBACK

Submit feedback for this data sheet.

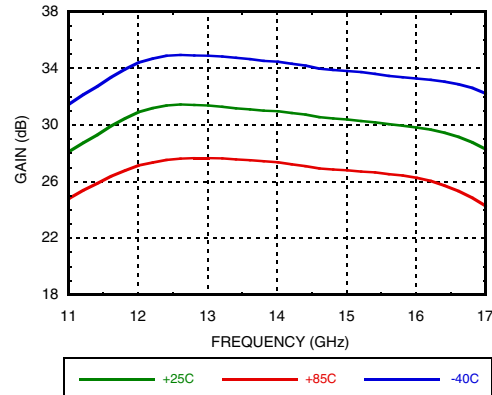
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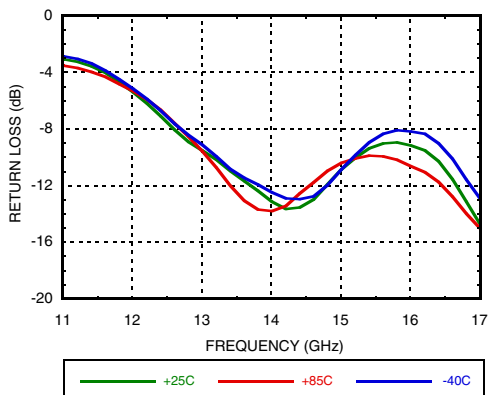
**Broadband Gain &
Return Loss vs. Frequency**



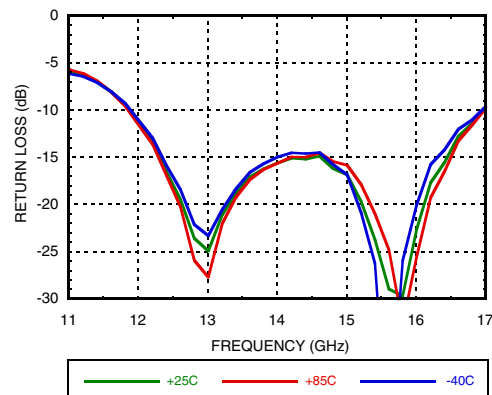
Gain vs. Temperature



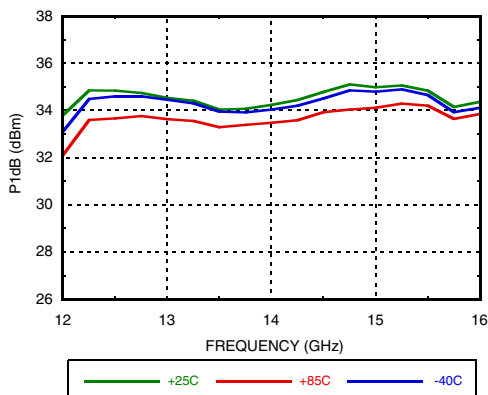
Input Return Loss vs. Temperature



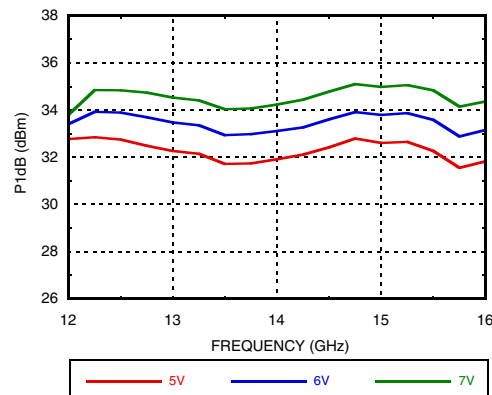
Output Return Loss vs. Temperature



P1dB vs. Temperature



P1dB vs. Supply Voltage



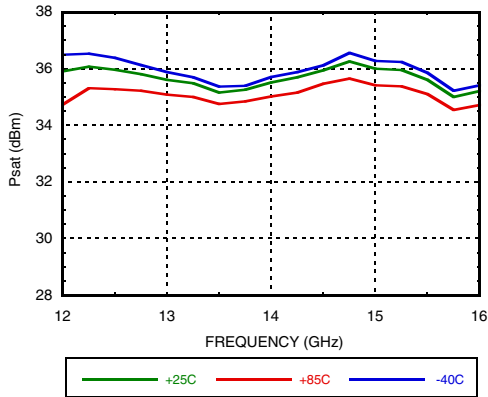
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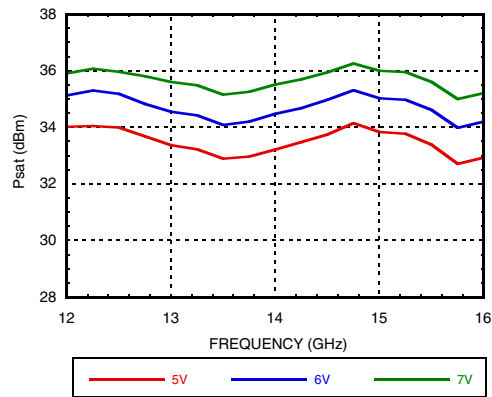
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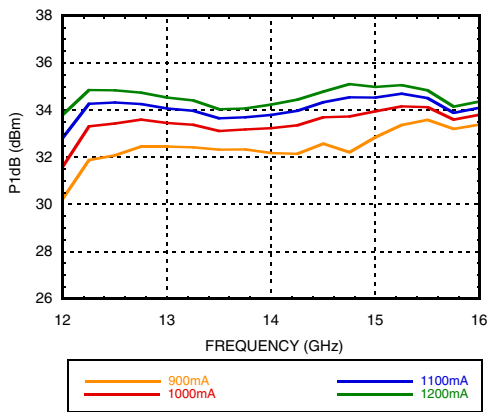
Psat vs. Temperature



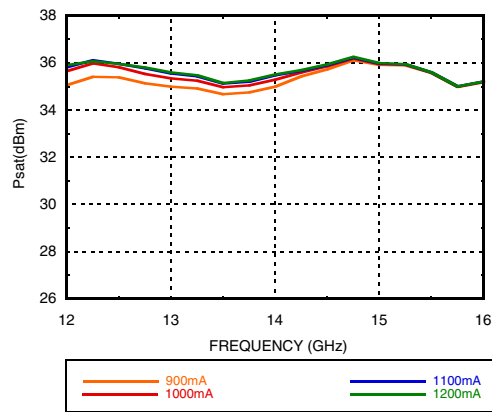
Psat vs. Supply Voltage



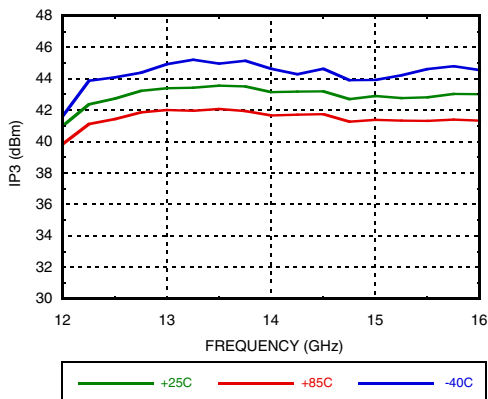
P1dB vs. Supply Current (Idd)



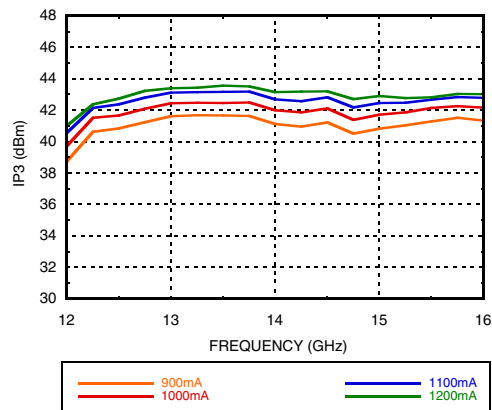
Psat vs. Supply Current (Idd)



Output IP3 vs. Temperature, Pout/Tone = +22 dBm



Output IP3 vs. Supply Current, Pout/Tone = +22 dBm

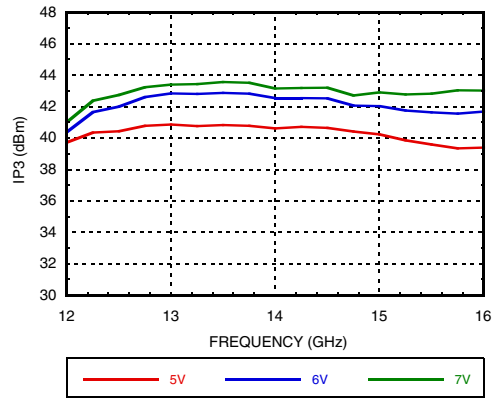


[1] Footnote if needed

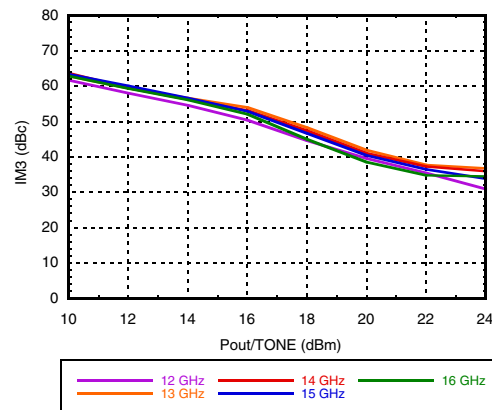
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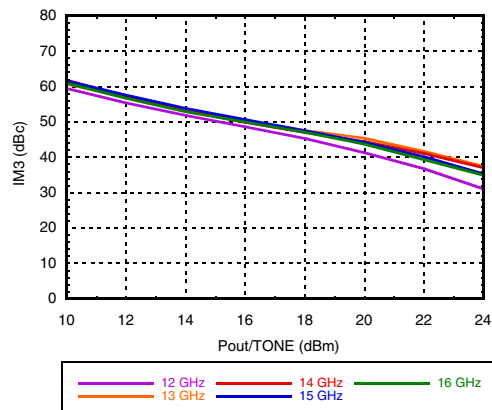
Output IP3 vs. Supply Voltage, Pout/Tone = +22 dBm



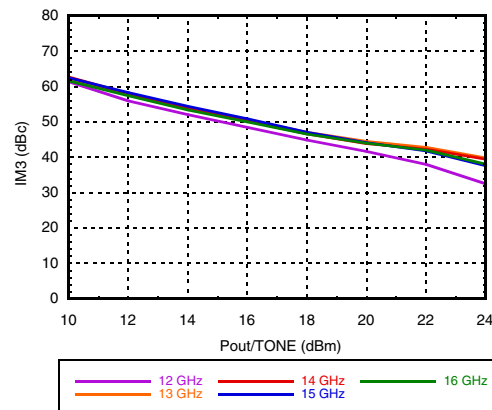
Output IM3 @ Vdd = +5V



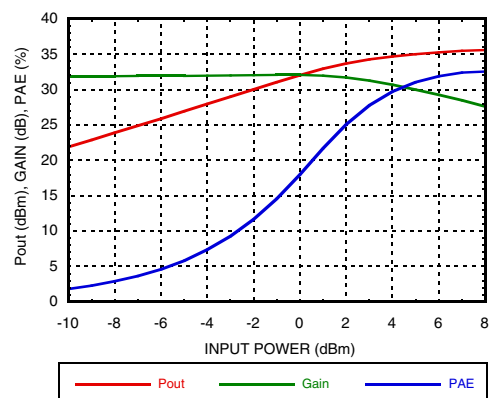
Output IM3 @ Vdd = +6V



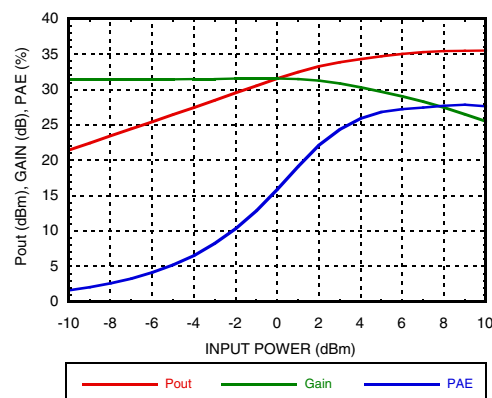
Output IM3 @ Vdd = +7V



Power Compression @ 13 GHz



Power Compression @ 14 GHz



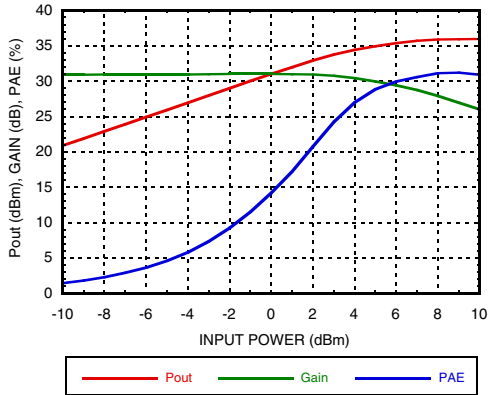
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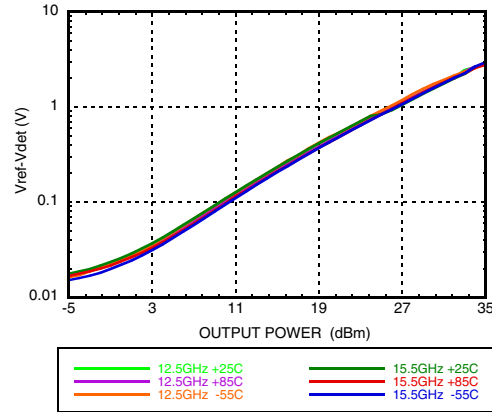
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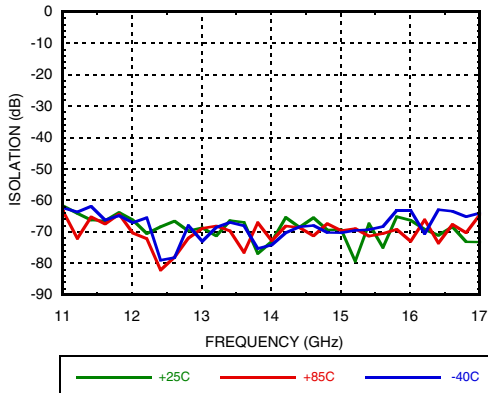
Power Compression @ 15 GHz



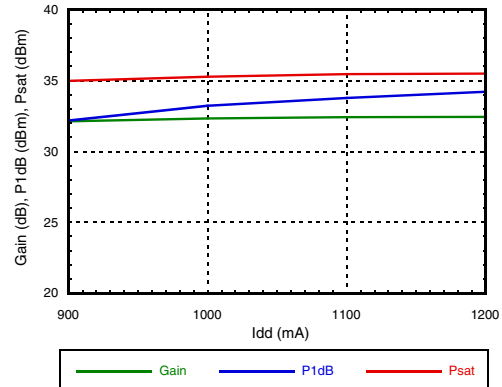
Detector Voltage Over Temperature



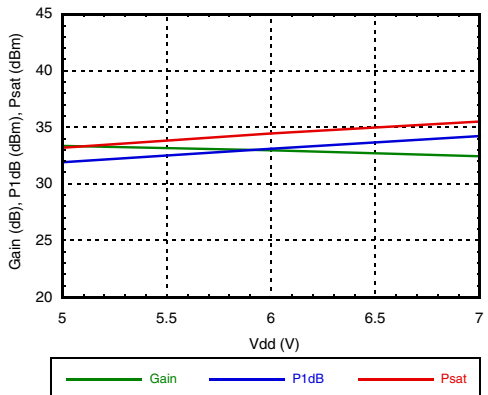
Reverse Isolation vs. Temperature



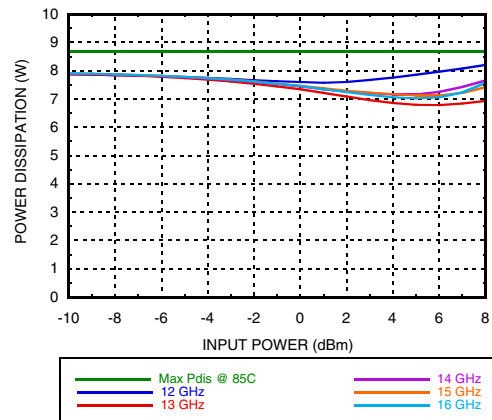
Gain & Power vs. Supply Current @ 14 GHz



Gain & Power vs. Supply Voltage @ 14 GHz



Power Dissipation



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GaAs pHEMT MMIC 2 WATT POWER AMPLIFIER WITH POWER DETECTOR, 12 - 16 GHz



Absolute Maximum Ratings

| | |
|---|--------------------|
| Drain Bias Voltage (V _{dd}) | +8V |
| RF Input Power (RFIN) | +24 dBm |
| Channel Temperature | 150 °C |
| Continuous P _{diss} (T= 85 °C) (derate 133 mW/°C above 85 °C) | 8.6 W |
| Thermal Resistance (channel to ground paddle) | 7.55 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -55 to +85 °C |
| ESD Sensitivity (HBM) | Class 1A Pass 250V |

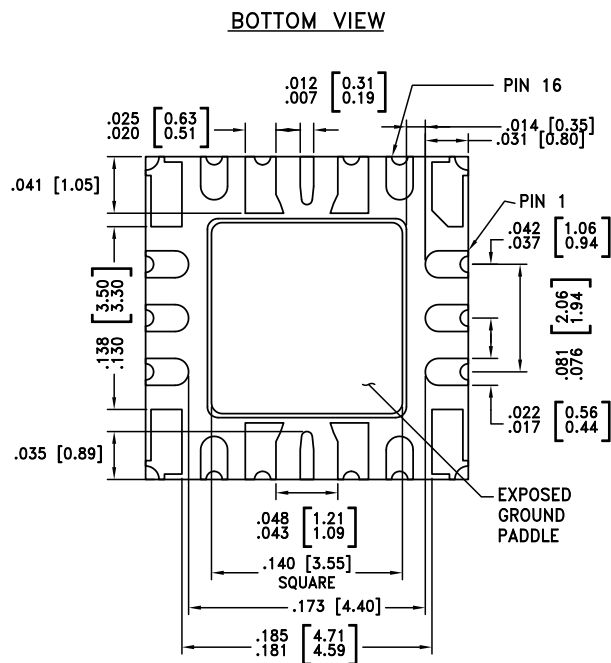
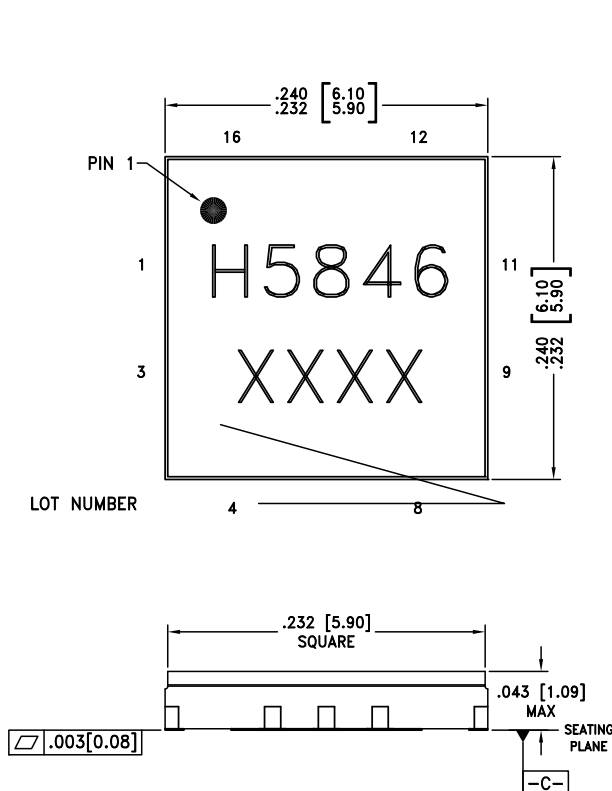
Reliability Information

| | |
|---|---------------|
| Junction Temperature to Maintain 1 Million Hour MTTF | 150 °C |
| Nominal Junction Temperature (T= 85 °C and Pin = 10 dBm) | 90 °C |
| Operating Temperature | -55 to +85 °C |



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating [2] | Package Marking [1] |
|-------------|-----------------------|------------------|----------------|---------------------|
| HMC5846LS6 | ALUMINA WHITE | Gold over Nickel | N/A | H5846 XXXX |

[1] 4-Digit lot number XXXX

[2] Max peak reflow temperature of 260 °C

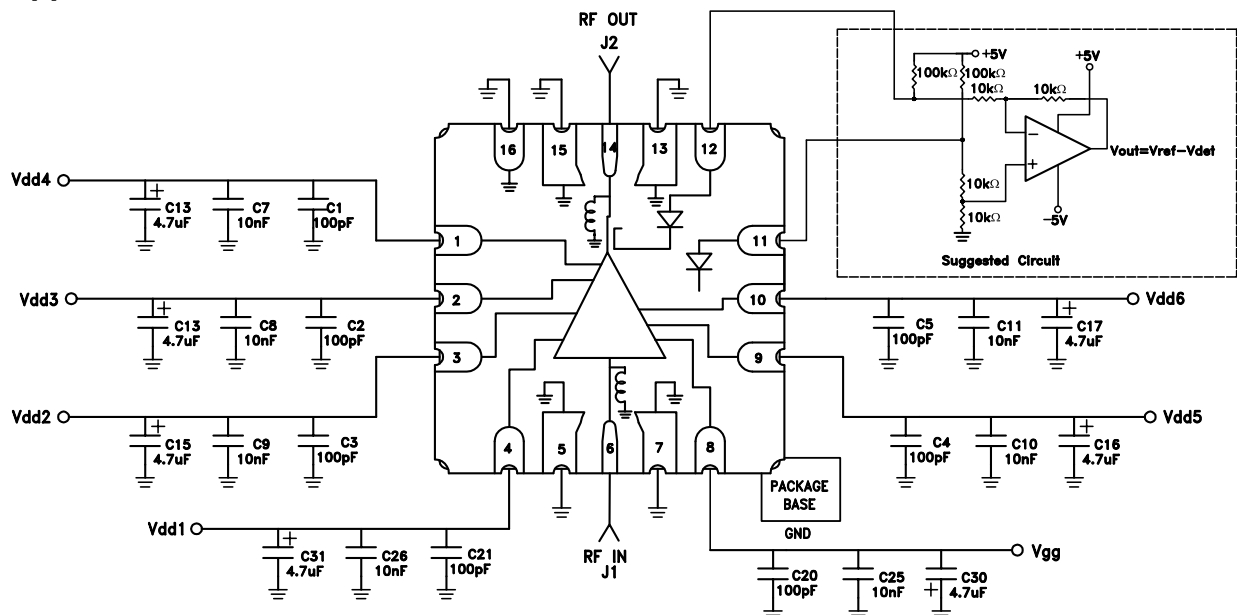
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Pin Descriptions

| Pad Number | Function | Description | Interface Schematic |
|------------------|------------------------------------|--|---------------------|
| 6 | RFIN | This Pin is DC coupled and matched to 50 Ohms over the operating frequency. | |
| 1-4 9, 10 | Vdd4, Vdd3, Vdd2, Vdd1, Vdd5, Vdd6 | Drain bias voltage for the amplifier. External bypass capacitors of 100 pF are required for each pin followed by 0.01 μF capacitors and a 4.7 μF capacitors. | |
| 8 | Vgg1 | Gate controlled amplifier. External bypass capacitors of 100 pF are required followed by 0.01 μF capacitors and a 4.7 μF capacitors. | |
| 5, 7, 13, 15, 16 | GND | These Pins and Package bottom must be connected to RF/DC ground. | |
| 11 | Vref | DC voltage of diode biased through external resistor, used for temperature compensation of Vdet. | |
| 12 | Vdet | DC voltage representing RF output rectified by diode which is biased through an external resistor. | |
| 14 | RFOUT | This Pin is DC coupled and matched to 50 Ohms. | |

Application Circuit



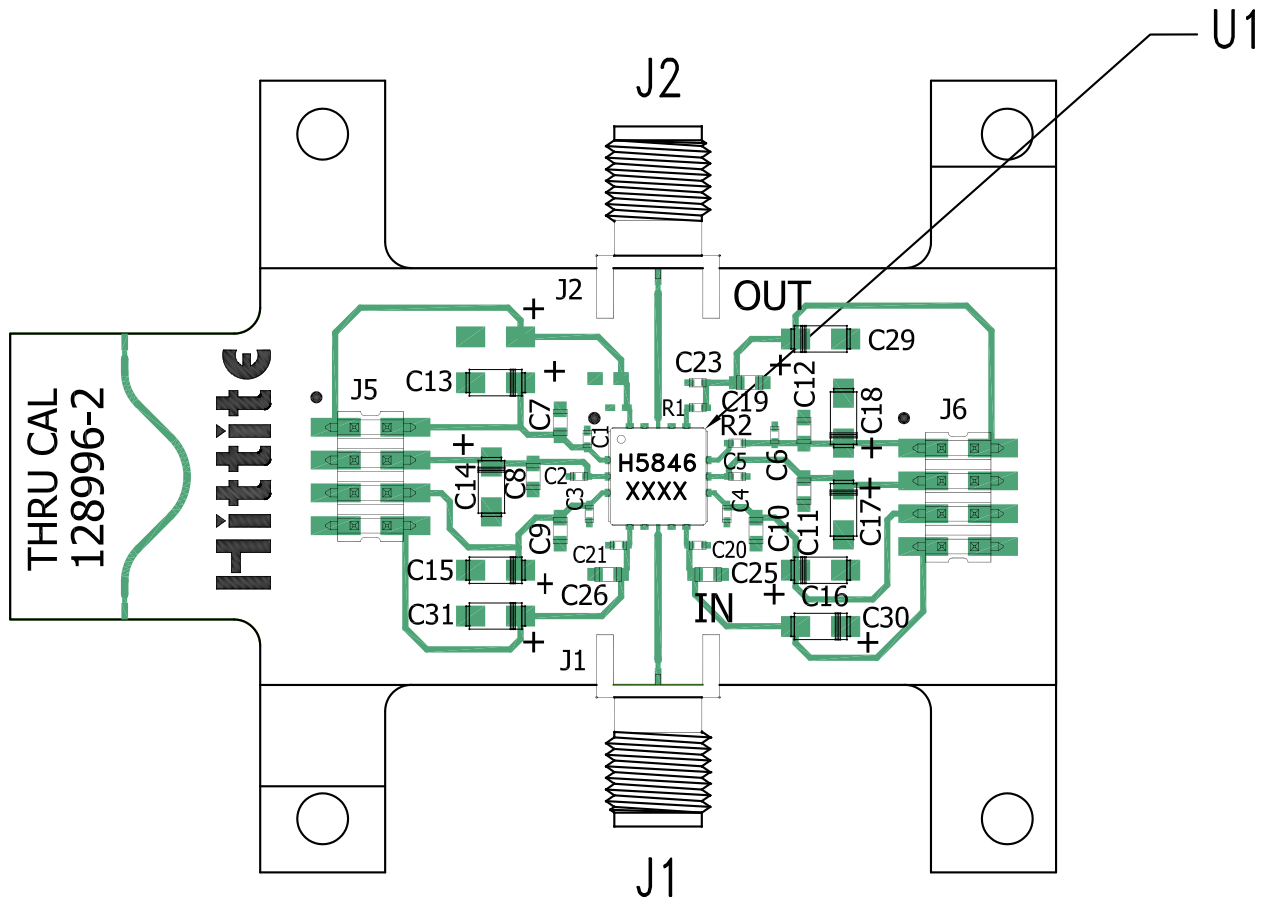
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Evaluation PCB



List of Materials for Evaluation PCB EVAL01-HMC5846LS6 [1]

| Item | Description |
|-------------------------|-------------------------------------|
| J1, J2 | PCB Mount K Connectors, SRI |
| J5, J6 | DC Pins |
| C1 - C6, C20, C21, C23 | 100 pF Capacitors, 0402 Pkg. |
| C7 - C12, C19, C25, C26 | 0.01 μ F Capacitors, 0603 Pkg. |
| C13 - C18, C29 - C31 | 4.7 μ F Capacitors, Case A Pkg. |
| R1 - R2 | 40.2 kOhm Resistor, 0402 Pkg. |
| U1 | HMC5846LS6 Amplifier |
| PCB [2] | 128996 Evaluation PCB |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.